APPLICA	BL	E STANDA	RD								
DATING	Operating temperature rang			-40 °C to 105 ° C (Note1)		Storage temperature r	ange		-40 ° C to 10	5 ° C	
KATING	Vo	Voltage				Current	1 A				
	•			SPECIF	FICATI	ONS					
	ΙΤΕ	M		TEST METHOD		REQUIREMENTS			EMENTS	QT	AT
CONSTR			<u> </u>					-	_		I
General exa			Visually and by measuring instrument.			According to drawing.					×
Marking			Confirmed visually.								×
		HARACTE									
Contact resistance			1A DC.			Signal: 30 mΩ MAX, Shield: 60 mΩ MAX.				×	_
Contact resistance Millivolt level method			20 mV AC max, 0.1 mA(DC or 1000Hz)			Signal: 30 m Ω MAX, Shield: 60 m Ω MAX .				×	_
Insulation resistance			500 V DC			100ΜΩ ΜΙΝ				×	<u> </u>
Voltage proof			650 V AC for 1 min.			No flashover or breakdown.				×	_
		L CHARAC	TERIST	ICS		II.					1
Mechanical operation			30 times insertions and extractions.			① Signal:60m Ω MAX, Shield:120m Ω MAX.				×	
						② No damage, crack and looseness of parts.				^	
Vibration			Frequency 20 to 200 Hz, 43.1 m/s ² at 3 h for 3 directions.			1 No electrical discontinuity of 10 µs.					
						- 0	Signal: $60m\Omega$ MAX, Shield: $120m\Omega$ MAX. No damage, crack and looseness of parts.				
Shock			Frequency 20 to 50 Hz,								
SHOCK	Snock			² at 1 h.	 No electrical discontinuity of 10 μs. Signal:60mΩ MAX, Shield:120mΩ MAX. 						
						③ No damage, crack and looseness of parts.					-
Lock strengt	h		Applying a pull force the mating axially at 98N max.			① During	applying,	matin	g completely.	×	
						② After applying, no defect of mating parts.					
	IME	NTAL CHA									
Damp heat	1		Exposed at 60 °C, 90 ~ 95 %, 500 h.			_			nield:120mΩ MAX.	×	
(Steady state	(Steady state)						② Insulation resistance:100 MΩ MIN.③ No damage, crack and looseness of parts.				-
Thermal sho	ck		Temperature-40→5 to 35→ 85→5 to 35°C			① Signal: $60m\Omega$ MAX, Shield: $120m\Omega$ MAX.					
				Time $30 \rightarrow 5 \rightarrow 30 \rightarrow 5 \text{ min}$			2 Insulation resistance:100 M Ω MIN.				_
- , ,			Under 1000 cycles.			③ No damage, crack and looseness of parts.					
Dry heat			Exposed at 105°C, 1000 h.			① Signal:60mΩ MAX, Shield:120mΩ MAX.				×	_
Cold	Cold			at -40°C , 1000 h.		② No damage, crack and looseness of parts. ① Signal:60mΩ MAX, Shield:120mΩ MAX.					
Cold			Exposed at 40 0 , 1000 II.			② No damage, crack and looseness of parts.				×	_
Resistance to SO ₂			Exposed in 500 ppm for 8h.			Signal:60mΩ MAX, Shield:120mΩ MAX.					_
Resistance to			Soldered at specified temperature profile			No deformation of case of excessive looseness of				×	_
soldering heat			2 times.			the terminals.					
COUN	١T	DE	SCRIPTIO	N OF REVISIONS		DESIGNED		CHECKED			TE
<u> </u>											
REMARK	the to	emnerature risin	a by current.				APPROVED		KI. HIROKAWA	+	00326
(Note 1) Include the temperature rising			g ,				CHECKI		EJ. WAKATSUKI	2020032	
							DESIGN		TS. KUBOTA	-	00325
							DRAWN		YK. MITSUISHI	20200221	
Note QT:Q	ualif	fication Test	AT:Assura	T:Assurance Test X:Applicable Test			G NO.		ELC-169398-56-00)
WС		SPECIFICATION SHEET				PART NO.	GT17HN2-4DP-2H(C)(56)				
₩5			OSE ELECTRIC CO., LTD.			CODE NO.	ODE NO. CL767-0295		-0295-1-56	\Diamond	1/1

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